



# **Cognitive-IoV with Simultaneous Sensing and Communications via Dynamic RF Front-End, Award No. 2128570**

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# Dynamic RF Front-Ends

Time-varying transmission lines (TVTL) and filters consist of passive transmissionlines and resonators in which the inductance or capacitance is modulated by the voltage of an electromagnetic wave called pump wave – hence the "time-varying" aspect. They can be used as fundamental building blocks that to create RF front-ends that are capable of advanced signal processing. The operation of these circuits possess both passive and active characteristics. They are fundamentally low loss and low noise - comparable to that of passive components. while the parametric gain of the timevarying operation can be used to compensate for the loss of the passive components and improve the overall noise performance





The two frequencies, the original RF and the up-converted RF, are crosscoupled through a carrier tone. By properly choosing the modulation frequency, the upper-sideband can be pushed beyond the cutoff, leaving only the signals at the two frequencies to propagate. As such, the TV device can be modeled as a 4-port linear network. This enables cross-coupling between the two tones ( $\omega_s$  and  $\omega_{p-s}$ ).

## Tunable Bandpass Filter

*Figure 1: Time-varying transmission line. Capacitance per unit length is a function of time and space*

An interesting feature can be noted when feedback and resonance is introduced to the TVTL. The feedback enables the circuit to accumulate a strong resonance and produce a large parametric gain. This amplification effect features extremely high Q, high gain, low noise, and high frequency selectivity.



#### Tunable Peak Amplifier

*Figure 3: Representation of the TV device by a fourport linear network*

 $\begin{bmatrix} \tilde{V}_s^-(z) \\ \tilde{V}_{m-s}^{*-}(z) \end{bmatrix} = \begin{bmatrix} t_{11} & t_{12} \\ t_{21} & t_{22} \end{bmatrix} \begin{bmatrix} \tilde{V}_s^+(0) \\ \tilde{V}_{m-s}^{*+}(0) \end{bmatrix}$ 

*Equation 1: Matrix Equation between outgoing and incoming signals at the two tones*

 $Z_0, \phi$ 

*Figure 4: Representation of the Tunable Peak Amplifier using the TVTL*

$$
\tilde{V}_s^-(z) = \left(t_{11} + \frac{t_{12}t_{21}}{1 - t_{22}}\right)\tilde{V}_s^+(0) = G_{ss}\tilde{V}_s^+(0)
$$

*Equation 2: Gain Equation at the original signal frequency for the Tunable Peak Amplifier*







$$
\tilde{V}_{out}(z) = \frac{t_{12}t_{21}}{1 - t_{22}^2} \tilde{V}_{in}(0) = G_{ss}\tilde{V}_{in}(0)
$$

*Equation 3: Gain Equation at the original signal frequency for the Tunable Bandpass Filter*

Another approach is to transform the tunable bandpass amplifier into a tunable bandpass filter. This not only amplifies the in-band signal, but also attenuates the outof-band frequencies.

*Figure 6: Simulation results (left) and measured results (right) for the tunable peak amplifier showcasing frequency selectivity and tunability*

*Figure 2: Physical realization of MI-TVTL consisting of microstrip line periodically loaded with varactor diodes*

### **Basic Operation**





*Figure 5: Representation of Tunable Bandpass Filter using the TVTL*



